# **HEF4541B**

# Programmable timer Rev. 4 — 25 June 2012

Product data sheet

#### **General description** 1.

The HEF4541B is a programmable timer which consists of a 16-stage binary counter, an integrated oscillator to be used with external timing components, an automatic power-on reset and output control logic. The frequency of the oscillator is determined by the external components R<sub>TC</sub> and C<sub>TC</sub> within the frequency range 1 Hz to 100 kHz. This oscillator may be replaced by an external clock signal at input RS, the timer advances on the positive-going transition of RS. A LOW on the auto reset input (AR) and a LOW on the master reset input (MR) enables the internal power-on reset. A HIGH level at input MR resets the counter independent on all other inputs. Resetting disables the oscillator to provide no active power dissipation.

A HIGH at input AR turns off the power-on reset to provide a low quiescent power dissipation of the timer. The 16-stage counter divides the oscillator frequency by 28, 210, 2<sup>13</sup> or 2<sup>16</sup> depending on the state of the address inputs (A0, A1). The divided oscillator frequency is available at output O. The phase input (PH) features a complementary output signal. When the mode select input (MODE) is LOW the timer is a single transition timer and when HIGH the timer is a 2<sup>n</sup> frequency divider.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to  $V_{DD}$ ,  $V_{SS}$ , or another input.

#### Features and benefits 2.

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Operates across the automotive temperature range –40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

#### Ordering information 3.

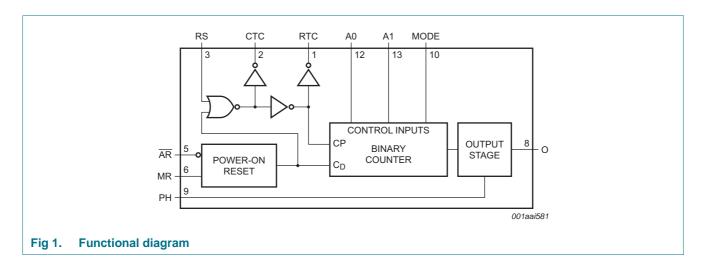
Table 1. **Ordering information** 

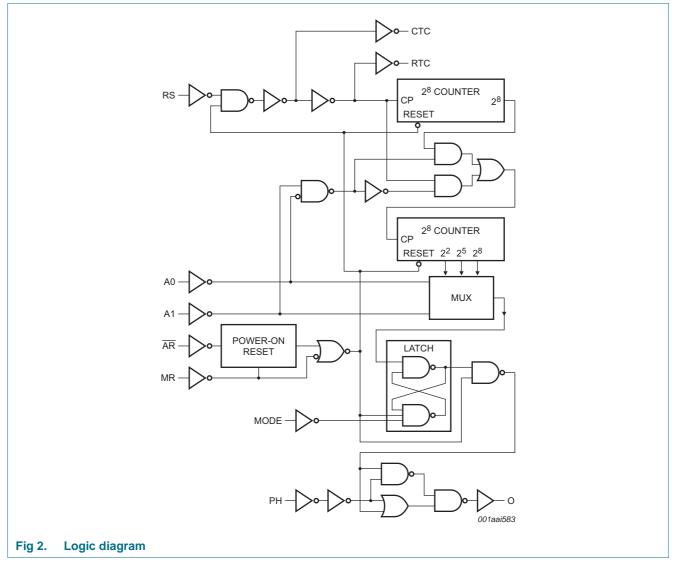
All types operate from −40 °C to +85 °C.

Type number	Package					
	Name	Description	Version			
HEF4541BP	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1			
HEF4541BT	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1			



## 4. Functional diagram

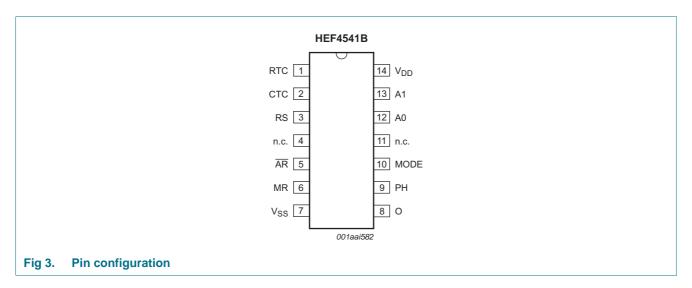




HEF4541B

# 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
RTC	1	external resistor connection
CTC	2	external capacitor connection
RS	3	external resistor connection (RS) or external clock input
nc	4, 11	not connected
ĀR	5	auto reset input (active low)
MR	6	master reset input
V <sub>SS</sub>	7	ground (0 V)
0	8	timer output
PH	9	phase input
MODE	10	mode select input
A0, A1	12, 13	address inputs
$V_{DD}$	14	supply voltage

## 6. Functional description

Table 3. Function table[1]

Input			MODE	
AR	MR	PH	MODE	
Н	L	X	X	auto reset disabled
L	L	X	Χ	auto reset enabled[2]
Χ	Н	Χ	X	master reset active
Χ	L	Χ	Н	normal operation selected division to output
Χ	L	Χ	L	single-cycle mode[3]
Χ	L	L	Χ	output initially LOW after reset
Χ	L	Н	Х	output initially HIGH, after reset

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care.

Table 4. Frequency selection table

A0	A1	Number of counter stages n	$\frac{f_{OSC}}{f_O} = 2^n$
L	L	13	8192
L	Н	10	1024
Н	L	8	256
Н	Н	16	65536

## 7. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	$V_{DD} + 0.5$	V
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I <sub>I/O</sub>	input/output current	O output	-	±10	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +85  ^{\circ}\text{C}$			
		DIP14 package	<u>[1]</u> -	750	mW
		SO14 package	[2] _	500	mW
Р	power dissipation		-	100	mW

<sup>[1]</sup> For DIP14 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

F4541B All information provided in this document is subject to legal disclaimers.

<sup>[2]</sup> For correct power-on reset, the supply voltage should be above 8.5 V. For V<sub>DD</sub> < 8.5 V, disable the autoreset and connect AR to V<sub>DD</sub>.

<sup>[3]</sup> The timer is initialized on a reset pulse and the output changes state after 2<sup>n-1</sup> counts and remains in that state (latched). Reset of this latch is obtained by master reset or by a LOW to HIGH transition on the MODE input.

<sup>[2]</sup> For SO14 package: Ptot derates linearly with 8 mW/K above 70 °C.

## 8. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		3	15	V
VI	input voltage		0	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5 V$	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	0.08	μs/V

## 9. Static characteristics

Table 7. Static characteristics

 $V_{SS} = 0$  V;  $V_I = V_{SS}$  or  $V_{DD}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> =	25 °C	T <sub>amb</sub> =	Unit	
				Min	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level	I <sub>O</sub>   < 1 μA	5 V	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
$V_{IL}$	LOW-level	I <sub>O</sub>   < 1 μA	5 V	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V <sub>OH</sub>	HIGH-level	I <sub>O</sub>   < 1 μA	5 V	4.95	-	4.95	-	4.95	-	V
	output voltage		10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V <sub>OL</sub>	LOW-level	LOW-level $ I_O  < 1 \mu A$ output voltage	5 V	-	0.05	-	0.05	-	0.05	V
	output voltage		10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I <sub>OH</sub>	HIGH-level	CTC, RTC;								
	output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.4	-	-1.2	-	-0.95	mA
		V <sub>O</sub> = 4.6 V	5 V	-	-0.5	-	-0.4	-	-0.3	mA
		V <sub>O</sub> = 9.5 V	10 V	-	-1.4	-	-1.2	-	-0.95	mA
		V <sub>O</sub> = 13.5 V	15 V	-	-4.8	-	-4.0	-	-3.2	mA
		О;								
		V <sub>O</sub> = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	mA
		V <sub>O</sub> = 4.6 V	5 V	-	-0.64	-	-0.5	-	-0.36	mA
		V <sub>O</sub> = 9.5 V	10 V	-	-1.6	-	-1.3	-	-0.9	mΑ
		V <sub>O</sub> = 13.5 V	15 V	-	-4.2	-	-3.4	-	-2.4	mΑ

 Table 7.
 Static characteristics ...continued

 $V_{SS} = 0$  V;  $V_{I} = V_{SS}$  or  $V_{DD}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> =	25 °C	T <sub>amb</sub> =	85 °C	Unit
				Min	Max	Min	Max	Min	Max	
$I_{OL}$	LOW-level	CTC, RTC;	'	'			•	•		'
	output current	$V_0 = 0.4 \ V$	5 V	0.33	-	0.27	-	0.20	-	mΑ
		$V_{O} = 0.5 \ V$	10 V	1.0	-	0.85	-	0.68	-	mA
		V <sub>O</sub> = 1.5 V	15 V	3.2	-	2.7	-	2.3	-	mΑ
		O;								
		$V_0 = 0.4 \ V$	5 V	0.64	-	0.5	-	0.36	-	mΑ
		$V_{O} = 0.5 \text{ V}$	10 V	1.6	-	1.3	-	0.9	-	mΑ
		$V_0 = 1.5 \text{ V}$	15 V	4.2	-	3.2	-	2.4	-	mA
I <sub>I</sub>	input leakage current		15 V	-	±0.1	-	±0.1	-	±1.0	μΑ
$I_{DD}$	supply current	$I_O = 0 A$	5 V	-	5	-	5	-	150	μΑ
			10 V	-	10	-	10	-	300	μΑ
			15 V	-	20	-	20	-	600	μΑ
Cı	input capacitance	)	-	-	-	-	7.5	-	-	pF

#### Table 8. Reset characteristics

 $V_{SS} = 0 \ V$ ;  $V_I = V_{SS}$  or  $V_{DD}$ ; see <u>Table 12</u> for test conditions; unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>DD</sub>	T <sub>amb</sub> =	–40 °C	Tam	<sub>nb</sub> = +25	°C	T <sub>amb</sub> =	+85 °C	Unit	
				Min	Max	Min	Тур	Max	Min	Max		
$I_{DD}$	supply current	supply current for	5 V	-	80	-	20	80	-	230	μΑ	
		power-on reset enable:	•	10 V	-	750	-	250	600	-	700	μΑ
	$\overline{AR}$ =	$\overline{AR} = MR = 0 \text{ V; Other}$ inputs at 0 V or $V_{DD}$	15 V	-	1.6	-	0.5	1.3	-	1.5	mA	
$V_{DD}$	supply voltage	supply voltage for automatic reset initialization; $\overline{AR} = MR = 0 \text{ V}$ ; Other inputs at 0 V or V <sub>DD</sub>	-	-	-	8.5	5	-	-	-	V	

## 10. Dynamic characteristics

Table 9. Dynamic characteristics

 $V_{SS} = 0 \text{ V}$ ;  $T_{amb} = 25 \,^{\circ}\text{C}$  unless otherwise specified. For test circuit, see <u>Figure 5</u>.

Symbol	Parameter	Conditions	$V_{DD}$		Extrapolation formula	Min	Typ[1]	Max	Unit
t <sub>pd</sub>	propagation delay	RS to O;	5 V	[2]	$348 \text{ ns} + (0.55 \text{ ns/pF})C_L$	-	375	750	ns
		2 <sup>8</sup> selected; see Figure 4	10 V		139 ns + (0.23 ns/pF)C <sub>L</sub>	-	150	300	ns
		see <u>rigule 4</u>	15 V		102 ns + (0.16 ns/pF)C <sub>L</sub>	-	110	220	ns
		RS to O;	5 V		398 ns + (0.55 ns/pF)C <sub>L</sub>	-	425	850	ns
		2 <sup>10</sup> selected; see Figure 4	10 V		154 ns + (0.23 ns/pF)C <sub>L</sub>	-	165	330	ns
		see <u>rigule 4</u>	15 V		112 ns + (0.16 ns/pF)C <sub>L</sub>	-	120	240	ns
		RS to O;	5 V		483 ns + (0.55 ns/pF)C <sub>L</sub>	-	510	1020	ns
		2 <sup>13</sup> selected;	10 V		179 ns + (0.23 ns/pF)C <sub>L</sub>	-	190	380	ns
		see Figure 4	15 V		127 ns + (0.16 ns/pF)C <sub>L</sub>	-	135	270	ns
		RS to O; 2 <sup>16</sup> selected;	5 V		548 ns + (0.55 ns/pF)C <sub>L</sub>	-	575	1150	ns
			10 V		199 ns + (0.23 ns/pF)C <sub>L</sub>	-	210	420	ns
		see <u>Figure 4</u>	15 V		142 ns + (0.16 ns/pF)C <sub>L</sub>	-	150	300	ns
t <sub>W</sub>	pulse width	RS LOW;	5 V	[3]		60	30	-	ns
		MR HIGH; see Figure 4	10 V			30	15	-	ns
		see <u>Figure 4</u>	15 V			24	12	-	ns
f <sub>clk(max)</sub>	maximum clock	RS; see Figure 4	5 V			8	16	-	MHz
	frequency		10 V			15	30	-	MHz
			15 V			18	36	-	MHz
f <sub>osc</sub>	oscillator frequency	$R_t = 5 \text{ k}\Omega;$	5 V			-	90	-	kHz
		$C_t = 1 \text{ nF};$ $R_S = 10 \text{ k}\Omega;$	10 V			-	90	-	kHz
		$R_S = 10 \text{ kg2},$ $See \underline{Figure 6}$	15 V			-	90	-	kHz
		$R_t = 56 \text{ k}\Omega;$	5 V			-	8	-	kHz
		$C_t = 1 \text{ nF};$	10 V			-	8	-	kHz
		$R_S = 120 \text{ k}\Omega;$ see Figure 6	15 V			-	8	-	kHz

<sup>[1]</sup> The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

<sup>[2]</sup>  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

<sup>[3]</sup>  $t_W$  is the same as  $t_{WL(min)}$  and  $t_{WH(min)}$ .

Table 10. Dynamic power dissipation

 $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0 \text{ V}$ ;  $t_r = t_f \le 20 \text{ ns}$ ;  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ .

Symbol	Darameter	V	Typical formula
Symbol	Parameter	$V_{DD}$	Typical formula
Per packa	ge		
P <sub>D</sub>	dynamic power dissipation	5 V	$P_D = 1300 \times f_i + (f_o \times C_L \times V_{DD}^2) \mu W$
		10 V	$P_D = 5300 \times f_i + (f_o \times C_L \times V_{DD}^2) \mu W$
		15 V	$P_D = 12000 \times f_i + (f_o \times C_L \times V_{DD}^2) \mu W$
Using the	on-chip oscillator		
P <sub>D(Tot)</sub>	Total dynamic power dissipation	5 V	$P_D = 1300 \times f_{osc} + f_o C_L V_{DD}^2 + 2C_{TC} V_{DD}^2 f_{osc} + 10 V_{DD} \mu W$
		10 V	$P_D = 5300 \times f_{osc} + f_o C_L V_{DD}^2 + 2C_{TC} V_{DD}^2 f_{osc} + 100 V_{DD} \mu W$
		15 V	$P_D = 12000 \times f_{osc} + f_o C_L V_{DD}^2 + 2C_{TC} V_{DD}^2 f_{osc} + 400 V_{DD} \mu W$

<sup>[1]</sup>  $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;  $C_L$  = output load capacitance in pF;  $V_{DD}$  = supply voltage in V;  $f_{osc}$  = oscillator frequency in MHz;  $C_{TC}$  = timing capacitance in pF.

## 11. Waveforms

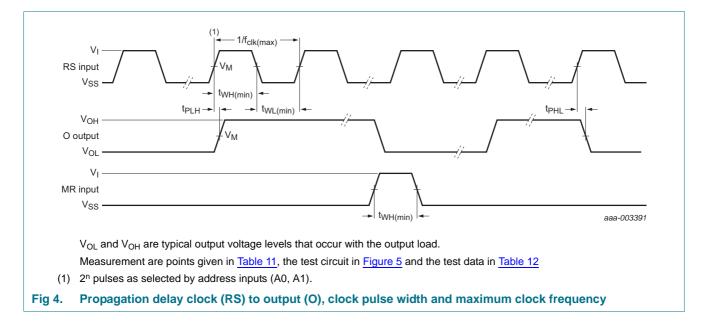
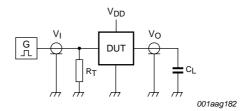


Table 11. Measurement points

Supply voltage	Input	Output
$V_{DD}$	V <sub>M</sub>	V <sub>M</sub>
5 V to 15 V	0.5V <sub>DD</sub>	0.5V <sub>DD</sub>



Test data is given in Table 12.

Definitions for test circuit:

DUT - Device Under Test.

 $R_L$  = Load resistance.

 $C_L$  = load capacitance.

 $R_T$  = Termination resistance should be equal to output impedance of  $Z_0$  of the pulse generator.

Fig 5. Test circuit for measuring switching times

#### Table 12. Test data

Supply	Input	Load	
$V_{DD}$	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL
5 V to 15 V	V <sub>SS</sub> or V <sub>DD</sub>	≤ 20 ns	50 pF

## 12. Application information

#### RC oscillator timing component limitations

The oscillator frequency is mainly determined by  $R_{TC}C_{TC}$ , provided  $R_{TC} << R_S$  and  $R_SC_2 << R_{TC}C_{TC}$ . The function of  $R_S$  is to minimize the influence of the forward voltage across the input protection diodes on the frequency. The stray capacitance  $C_2$  should be kept as small as possible. In consideration of accuracy,  $C_{TC}$  must be larger than the inherent stray capacitance.  $R_{TC}$  must be larger than the LOCMOS 'ON' resistance in series with it, which typically is 500  $\Omega$  at  $V_{DD}$  = 5 V, 300  $\Omega$  at  $V_{DD}$  = 10 V and 200  $\Omega$  at  $V_{DD}$  = 15 V.

The recommended values for these components to maintain agreement with the typical oscillation formula are:  $C_{TC} \ge 100$  pF, up to any typical value,  $10 \text{ k}\Omega \le R_{TC} \le 1 \text{ M}\Omega$ .

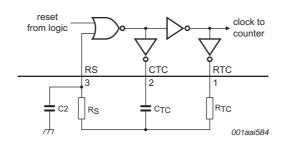
10<sup>5</sup>

10<sup>4</sup>

103

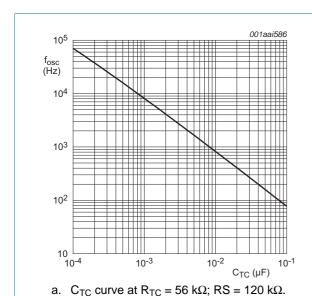
10<sup>2</sup>

f<sub>osc</sub> (Hz)



Typical formula for oscillator frequency:  $f_{\text{osc}} = \frac{1}{2.3 \times R_{TC} \times C_{TC}}$ 

Fig 6. External component connection for RC oscillator;  $R_S \approx R_{TC}$ 





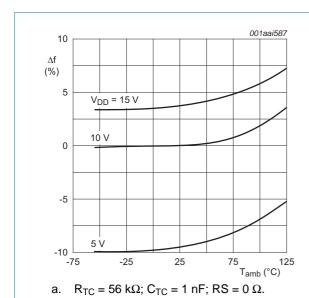
10<sup>4</sup>

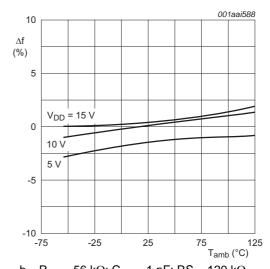


HEF4541E

001aai585







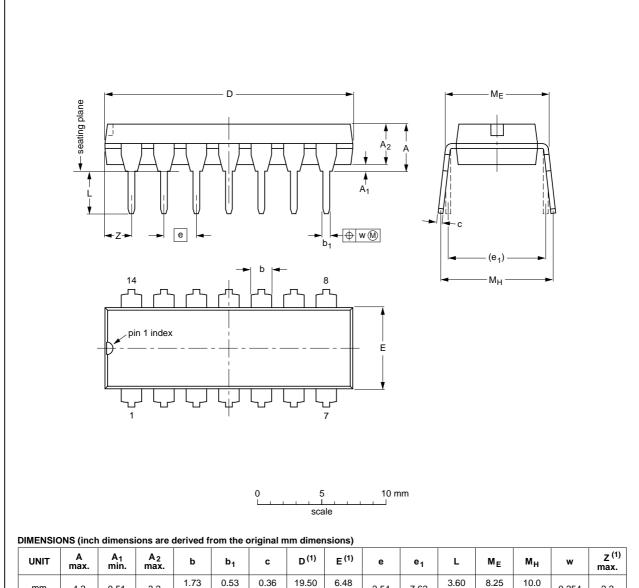
b.  $R_{TC}$  = 56  $k\Omega$ ;  $C_{TC}$  = 1 nF; RS = 120  $k\Omega$ .

Fig 8. Frequency deviation ( $\Delta f$ ) as a function of ambient temperature

## 13. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.02	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

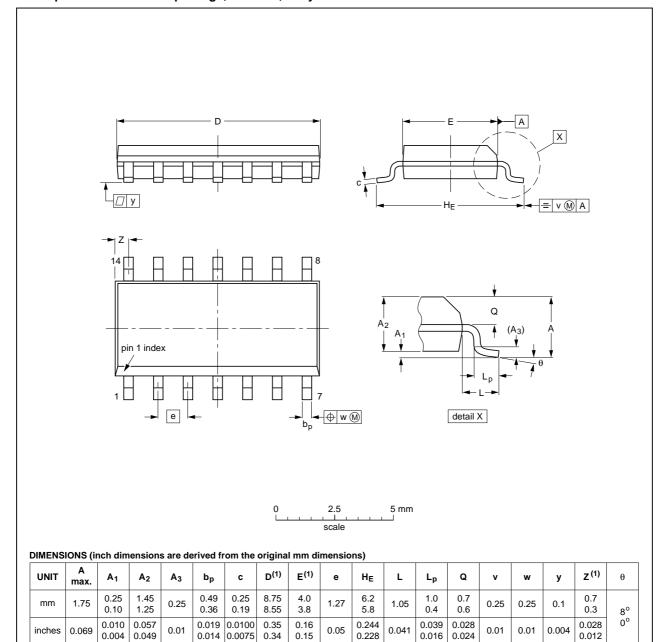
OUTLINE		REFER	ENCES	EUROPEAN ISSUE DA		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001	SC-501-14		<del>99-12-27</del> 03-02-13	

Fig 9. Package outline SOT27-1 (DIP14)

HEF4541B All information provided in this document is subject to legal disclaimers.

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DA		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012			<del>99-12-27</del> 03-02-19	

Fig 10. Package outline SOT108-1 (SO14)

All information provided in this document is subject to legal disclaimers.

## 14. Abbreviations

#### Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 15. Revision history

## Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
HEF4541B v.4	20120625	Product data sheet	-	HEF4541B_CNV v.3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>					
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
	<ul> <li>Section 2 "F</li> </ul>	eatures and benefits" added				
HEF4541B_CNV v.3	19950101	Product specification	-	HEF4541B_CNV v.2		
HEF4541B_CNV v.2	19950101	Product specification	-	-		

## 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

#### 16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

HEF4541B

All information provided in this document is subject to legal disclaimers.



**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### 16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com



## 18. Contents

1	General description
2	Features and benefits
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 3
5.1	Pinning
5.2	Pin description
6	Functional description 4
7	Limiting values 4
8	Recommended operating conditions 5
9	Static characteristics 5
10	Dynamic characteristics 7
11	Waveforms
12	Application information 10
	RC oscillator timing component limitations10
13	Package outline
14	Abbreviations14
15	Revision history
16	Legal information
16.1	Data sheet status
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks16
17	Contact information 16
18	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.